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CA, CH, CL, CN, CO, CR, CU, CZ, DE, DJ, DK, DM, DO, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IR, IS, JP, KE, KG, KH, KN, KP, KR, KW, KZ, LA, LC, LK, LR, LS, LU, LY, MA, MD, ME, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PA, PE, PG, PH, PL, PT, QA, RO, RS, RU, RW, SA, SC, SD, SE, SG, SK, SL, SM, ST, SV, SY, TH, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW.

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(54) Title: TUNABLE WAVEGUIDE SYSTEM

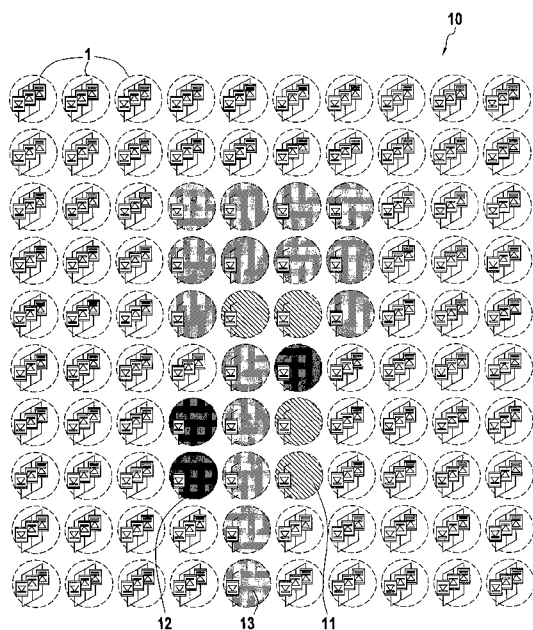


FIG. 7

(57) Abstract: The present disclosure relates to a tunable waveguide system comprising a waveguide configured to guide radio waves in at least two dimensions, and an electronically tunable metamaterial configured to tune the radio waves by electronically changing its dielectric and/or conductive characteristics. The present disclosure further relates to a radar antenna system.



Tunable waveguide system

FIELD OF THE DISCLOSURE

[0001] The present disclosure is related to a tunable waveguide system, in particular configured for a THz and/or submillimeterwave signal manipulation.

BACKGROUND OF THE DISCLOSURE

[0002] Tuning of waveguide circuits is done usually mechanically. However, due to the mechanical tuning, parts have to be moved. This leads to less accurate tuning, in particular accurate tuning of electronic circuits for THz and/or submillimeterwave applications becomes hardly feasible.

[0003] There have been several approaches in the prior art regarding this issue.

[0004] For example, WO 2001099224 A1 discloses electronically tunable dielectric composite thick films.

[0005] US 6686817 B2 refers to electronic tunable filters with dielectric varactors.

[0006] US 7462956 B2 discloses high efficiency NLTL comb generator using time domain waveform synthesis technique.

[0007] US 4529987 refers to a Broadband microstrip antennas with varactor diodes.

SUMMARY OF THE DISCLOSURE

[0008] Currently, it remains desirable to provide an accurately tunable waveguide system, in particular for THz and/or submillimeterwave signal manipulation.

[0009] Therefore, according to embodiments of the present disclosure, a tunable waveguide system is provided comprising a waveguide configured to guide radio waves in at least two dimensions, and an electronically tunable metamaterial configured to tune the radio waves by electronically changing its dielectric and/or conductive characteristics.

[0010] Accordingly, by adding a tunable metamaterial, waveguide and traditional circuits can be tuned or switched electronically without moving parts.

[0011] Schottky diodes or varactors may be used as atoms in a metamaterial. Applied bias voltage changes the electromagnetic behavior of the

material. Using photosensitive circuitry, the bias voltages may be created in the material itself by proper irradiation. Using resonant elements, bias voltages may be generated by low frequency fields. This can be used to manipulate the material and by this to change circuit behavior.

- 5 [0012] Tunability in circuits may hence be implemented by adding nonlinearities either as lumped elements or by adding nonlinear materials as layers.

[0013] The waveguide is desirably configured to guide radio waves in at least two dimensions. In other words, the waveguide may be a three-
10 dimensional waveguide (e.g. a waveguide having substantially a tube form). Said waveguide may to be distinguished from planar waveguides (also called slab waveguides), which are configured to guide waves in only one dimension.

[0014] The metamaterial may comprise non-linear elements, e.g. as lumped elements in the metamaterial, and/or non-linear materials provided in at least
15 one layer of the metamaterial.

[0015] The waveguide system may be configured to transmit radio waves with a predetermined wavelength, wherein the non-linear elements may be provided in the metamaterial in a distance smaller with regard to the wavelength of the radio waves, e.g. with a mean distribution of at least 5 non-
20 linear elements per wavelength, more in particular of at least 20 non-linear elements per wavelength.

[0016] The metamaterial may be configured to process the radio waves in a predetermined manner by changing its electromagnetic characteristics.

[0017] The metamaterial may be programmable to form a spatial filter, a
25 hologram, and/or a kinoform configured for microwave- millimeterwave- or THz-applications.

[0018] The waveguide system may be configured to transmit radio waves with a predetermined wavelength, wherein the metamaterial may be configured to have a dielectric characteristic, e.g. by homogenization of the non-linear
30 elements in a distance relatively small with regard to the wavelength of the radio waves, and/or the metamaterial is configured to have an at least pseudo-crystalline characteristic, e.g. a diffraction pattern, e.g. by Bragg analysis of the non-linear elements in a distance relatively large with regard to the wavelength of the radio waves.

[0019] By programming a certain set of nonlinear elements to have dielectric properties equal to their surroundings, these nonlinear elements become desirably invisible. Other elements may be programmed to show contrast to the embedding materials. These elements are desirably visible. The allowed and forbidden diffraction angles in a crystal (as known from the Art, e.g. Bragg's law) may therefore be mimicked and an efficient power switch be created by placing further processing electronics at directions from the crystal are located that can be turned on and off by changing the crystal parameters of the diffraction system.

[0020] The non-linear elements may be tunable by an applied bias voltage, the bias voltage being e.g. provided by photosensitive circuitries and/or provided by resonant electric elements.

[0021] The waveguide system may further comprise a bias electronic circuit configured to apply a bias voltage to the non-linear elements.

[0022] The non-linear elements may comprise varactors, e.g. a varactor array, and/or Schottky diodes, e.g. a Schottky diode array.

[0023] The metamaterial may be arranged such that the radio waves pass the metamaterial, the metamaterial being e.g. arranged in the waveguide, more in particular to form a layer across waveguide.

[0024] The present disclosure further relates to an antenna system, comprising: a waveguide system as described above configured to generate a radio output signal, e.g. at more than 100GHz.

[0025] The present disclosure further relates to a radar antenna system, comprising the antenna system as described above.

[0026] The present disclosure further relates to a radar antenna system, comprising an array of a plurality of antenna systems as described above.

[0027] It is intended that combinations of the above-described elements and those within the specification may be made, except where otherwise contradictory.

[0028] It is to be understood that both the foregoing general description and the following detailed description are exemplary and explanatory only and are not restrictive of the disclosure, as claimed.

[0029] The accompanying drawings, which are incorporated in and constitute a part of this specification, illustrate embodiments of the disclosure and together with the description, serve to explain the principles thereof.

BRIEF DESCRIPTION OF THE DRAWINGS

[0030] Fig. 1 shows a schematic representation of a crystal element (dotted circle) with direct biasing using wires according to an embodiment of the present disclosure;

[0031] Fig. 2 shows a schematic representation of a crystal element (dotted circle) with external biasing using resonant circuits according to an embodiment of the present disclosure;

[0032] Fig. 3 shows a schematic representation of a crystal element (dotted circle) with external biasing using (e.g. red) LED and photodiode according to an embodiment of the present disclosure;

[0033] Fig. 4 shows a schematic representation of a crystal element (dotted circle) with external biasing using (e.g. red and green) LED and photodiode according to an embodiment of the present disclosure;

[0034] Fig. 5 shows a schematic representation of a crystal element (dotted circle) with external biasing using (e.g. green) LED and photodiode and (e.g. red) LED and photoresistor according to an embodiment of the present disclosure;

[0035] Fig. 6 shows a schematic representation of an unprogrammed photonic crystal structure comprising a plurality of crystal elements according to an embodiment of the present disclosure;

[0036] Fig. 7 shows a schematic representation of an optically programmed photonic crystal structure according to an embodiment of the present disclosure; and

[0037] Fig. 8 shows a schematic representation of a circuit equivalent to the optically programmed photonic crystal structure of Fig. 7.

DESCRIPTION OF THE EMBODIMENTS

[0038] Reference will now be made in detail to exemplary embodiments of the disclosure, examples of which are illustrated in the accompanying drawings. Wherever possible, the same reference numbers will be used throughout the drawings to refer to the same or like parts.

[0039] In the present disclosure, nonlinear lumped elements may be added to a material and may be biased to change their dielectric properties. These changed properties may then be used to influence other electronics embedded

or in contact with the material or to influence signals passing through the material.

[0040] When adding said nonlinear elements at a density considerably smaller than the wavelength of operation, the overall dielectric behavior of the material may then be obtained by homogenization and the material exhibits anisotropic and uniform behavior.

[0041] Changing the bias voltage across the added nonlinear lumped elements, the dielectric function of the homogenized body may be changed. Having e.g. varactors as nonlinear elements, the capacitance of the varactors may be a maximum when no bias voltage is applied and shrinks when a positive bias voltage is present on the varactors. Therefore the dielectric function of the material may be reduced when a positive bias voltage is applied to the nonlinearities.

[0042] When adding said nonlinear elements at a density comparable to the wavelength of operation, the material may form a (periodic crystal, quasiperiodic pseudocrystal or a random) photonic structure.

[0043] The property of this structure may be tuned or switched on and off by applying suitable bias voltages to the nonlinear element.

[0044] Especially quasiperiodic structures (pseudocrystals) with arbitrary diffraction patterns may be generated in one and the same substrate by applying local bias voltages that correspond to the desired quasiperiodic structure.

[0045] A general problem of tunable material is that the bias voltage must be applied to the nonlinear elements. For this, this present disclosure offers three solutions as shown in fig. 1 (solution A), fig. 2 (solution B) and fig. 3 and 4 (solution C):

[0046] Fig. 1 shows a schematic representation of a crystal element 1, 2 (dotted circle) with direct biasing using wires 3 according to an embodiment of the present disclosure. Usage of bias lines with a wave impedance much higher than the wave impedance of operation of the circuit itself (c.f. Fig.1). Here additional High-Low-Z filter sections may be added to prevent signal coupling from the microwave signal and the bias line. Nevertheless, certain orientations of the bias wires (e.g. parallel to the electric field of the basic mode of signal propagation) must be avoided and puts a severe limit to the designer's freedom. This solution is known from Prior Art.

[0047] Fig. 2 shows a schematic representation of a crystal element 1 (dotted circle) with external biasing using resonant circuits 4, 5 according to an embodiment of the present disclosure. The bias voltage is transmitted using a chopped AC voltage V at a frequency very much smaller than the frequency of operation. Resonant loops 4, 5 are used to generate the required bias voltages locally. This solution requires no wiring to the exterior but requires external electronics to generate the electromagnetic resonances (c.f. Fig.2). Using various resonance frequencies, more than one type of nonlinear element may be biased independently as well.

10 [0048] Fig. 3 shows a schematic representation of a crystal element 1 (dotted circle) with external biasing using (e.g. red) LED 8 and photodiode 6 according to an embodiment of the present disclosure. The bias voltage is polarized in blocking direction of the varactor 2. Fig. 4 shows a schematic representation of a crystal element 1 (dotted circle) with external biasing using
15 (e.g. red and green) LED 8a, 8b and photodiodes 6a, 6b according to an embodiment of the present disclosure. The "red" bias voltage is polarized in blocking direction of the varactor, the "green" is polarized in forward direction. Photosensitive diodes may be used to generate the required bias voltages locally. This solution requires no external wiring but requires optical (visible or
20 IR) access to the material during operation (c.f. Fig.3). Using color filters, more than one type of nonlinear element may be biased independently (e.g. for programmable anisotropy or conductivity (c.f. Fig.4)). It is noted that the colors red and green are mere example.

[0049] Generally the tunable waveguide system may be configured to be
25 biased by light of one or several colors. In case of several colors, e.g. green and red, several non-linear elements may be tuned independently from each other (in particular orthogonally).

[0050] Depending on the application biasing schemes A,B and C may be used simultaneously.

30 [0051] Fig. 5 shows a schematic representation of a crystal element 1 (dotted circle) with external biasing using (e.g. green) LED 8a and photodiode 6a and (e.g. red) LED 8b and photoresistor 6b according to an embodiment of the present disclosure. The "green" voltage is polarized in forward direction and the "red" photon flow creates a conducting bridge between the element and its
35 neighbors.

[0052] Fig. 6 shows a schematic representation of an unprogrammed photonic crystal structure 10 comprising a plurality of crystal elements 1 according to an embodiment of the present disclosure. The photonic crystal structure 10 may be comprised by an electronically tunable metamaterial
5 according to the disclosure.

[0053] A photonic crystal without program is shown in Figure 6. Applying an image on the surface of the photonic crystal results in local change of the dielectric and ohmic behavior. Any spectral component in the "green" region will cause the crystal elements to become ohmically lossy. Any spectral
10 component in the "red" region will result in a reduction of the dielectric function.

[0054] A similar effect may be obtained with the resonant biasing scheme as well by applying several different resonant frequencies e.g. a lower frequency for the dielectric change and a higher frequency for the ohmic part of a
15 varactor biasing.

[0055] Please note that the additional separation circuits needed to avoid the forward bias to be shorted in the backward diodes have been omitted throughout these Figures for clarity's sake.

[0056] Fig. 7 shows a schematic representation of an optically programmed
20 photonic crystal structure according to an embodiment of the present disclosure. The "red" (i.e. in fig. 7 dashed) dots 11 are programmed to have a maximum reduced dielectric constant. The "pink" (i.e. in fig. 7 dark grey) dots 12 are programmed using the "red" optical channel with less power. The "green" (i.e. in fig. 7 light grey) dots 13 are programmed to be conducting. In
25 Figure 7 the "green" illumination creates a patch and a transmission line. The embedding dielectric is programmed using the red channel to yield a bandpass filter and to adapt the distance between the feed point and the patch cut to match the patch input impedance to the line impedance.

[0057] Fig. 8 shows a schematic representation of a circuit equivalent 10' to
30 the optically programmed photonic crystal structure of Fig. 7. In particular, Figure 8 shows the equivalent circuit as a surface to be used on a microstrip substrate.

[0058] Of course, Figure 7 is an extreme situation where no common electric parts are used in the previously used metal surface technology (as in

Figure 8). A more realistic approach is to use this invention in those parts and regions of a system, where tuning and programming yields a function benefit.

[0059] Examples are adaptive antennas, adaptive filters, DOA preprocessors etc.

5 [0060] The metamaterial may comprise (in particular as a substrate) a material like PLA (polyactide), any foam, and/or any known dielectric suitable for via hole production.

[0061] The non-linear elements may comprise GaAlAs varactors, desirably HBVs (heterostructure barrier varactors).

10 [0062] Additionally or alternatively the varactors may comprise heterostructure barrier varactors. This type of varactor is a special case of two varactors glued back to back.

[0063] The size of the non-linear objects may be between $200\mu\text{m}^3$ to 1mm^3 .

15 [0064] The distance between the nonlinear objects may be 1 to 10 times of their size and as close as possible. Additionally or alternatively an acceptable value for the distance between the nonlinear objects may be 0.1 wavelength of the radio waves or less.

[0065] The wavelength of the radio waves for which the waveguide is configured may be between 10cm (at 3GHz) to 1mm (at 300GHz).

20 [0066] The wavelength of the bias voltage applied to the non-linear elements may be selected to be larger and/or smaller than the wavelength of the radio waves, such that it does not interfere with the radio waves or interference is reduced.

25 [0067] The wavelength of bias voltage provided by resonant electric elements, (e.g. Using coils) may be larger than the wavelength of the radio waves, e.g. 1km to 10cm.

[0068] The wavelength of bias voltage bias voltage provided by photosensitive circuitries may be smaller than the wavelength of the radio waves, e.g. near infrared (e.g. $1\mu\text{m}$) through VIS until weak UV (e.g. 359nm).

30 [0069] Throughout the disclosure, including the claims, the term "comprising a" should be understood as being synonymous with "comprising at least one" unless otherwise stated. In addition, any range set forth in the description, including the claims should be understood as including its end value(s) unless otherwise stated. Specific values for described elements should
35 be understood to be within accepted manufacturing or industry tolerances

known to one of skill in the art, and any use of the terms "substantially" and/or "approximately" and/or "generally" should be understood to mean falling within such accepted tolerances.

5 [0070] Furthermore the terms like "upper", "upmost", "lower" or "lowest" and suchlike are to be understood as functional terms which define the relation of the single elements to each other but not their absolute position.

10 [0071] Where any standards of national, international, or other standards body are referenced (e.g., ISO, etc.), such references are intended to refer to the standard as defined by the national or international standards body as of the priority date of the present specification. Any subsequent substantive changes to such standards are not intended to modify the scope and/or definitions of the present disclosure and/or claims.

15 [0072] Although the present disclosure herein has been described with reference to particular embodiments, it is to be understood that these embodiments are merely illustrative of the principles and applications of the present disclosure.

[0073] It is intended that the specification and examples be considered as exemplary only, with a true scope of the disclosure being indicated by the following claims.

CLAIMS

1. A tunable waveguide system comprising:
a waveguide configured to guide radio waves in at least two dimensions, and
5 an electronically tunable metamaterial configured to tune the radio waves by electronically changing its dielectric and/or conductive characteristics.
2. The waveguide system according to claim 1, wherein
the metamaterial comprises non-linear elements, in particular as lumped
10 elements in the metamaterial, and/or non-linear materials provided in at least one layer of the metamaterial.
3. The waveguide system according to claim 1 or 2, configured to
transmit radio waves with a predetermined wavelength, wherein
15 the non-linear elements are provided in the metamaterial in a distance smaller with regard to the wavelength of the radio waves, in particular with a mean distribution of at least 5 non-linear elements per wavelength, more in particular of at least 20 non-linear elements per wavelength.
- 20 4. The waveguide system according to any one of the preceding claims, wherein the metamaterial is configured to process the radio waves in a predetermined manner by changing its electromagnetic characteristics.
5. The waveguide system according to any one of the preceding claims,
25 wherein the metamaterial is programmable to form a spatial filter, a hologram, and/or a kinoform configured for microwave- millimeterwave- or THz-applications.
6. The waveguide system according to any one of the preceding claims,
30 configured to transmit radio waves with a predetermined wavelength, wherein the metamaterial is configured to have a dielectric characteristic, in particular by homogenization of the non-linear elements in a distance relatively small with regard to the wavelength of the radio waves, and/or
the metamaterial is configured to have an at least pseudo-crystalline
35 characteristic, in particular a diffraction pattern, in particular by Bragg analysis

of the non-linear elements in a distance relatively large with regard to the wavelength of the radio waves.

7. The waveguide system according to any one of the preceding claims,
5 wherein the non-linear elements are tunable by an applied bias voltage,
the bias voltage being in particular provided by photosensitive circuitries and/or
provided by resonant electric elements.
8. The waveguide system according to any one of the preceding claims,
10 further comprising a bias electronic circuit configured to apply a bias voltage to
the non-linear elements.
9. The waveguide system according to any one of the preceding claims,
wherein the non-linear elements comprise varactors, in particular a varactor
15 array, and/or Schottky diodes, in particular a Schottky diode array.
10. The waveguide system according to any one of the preceding claims,
wherein metamaterial is arranged such that the radio waves pass the
metamaterial, the metamaterial being in particular arranged in the waveguide,
20 more in particular to form a layer across waveguide.
11. An antenna system, comprising:
a waveguide system according to any of the preceding claims configured to
generate a radio output signal, in particular at more than 100GHz.
25
12. A radar antenna system, comprising the antenna system of the
preceding claim 11, in particular an array of a plurality of antenna systems of
the preceding claim 11.

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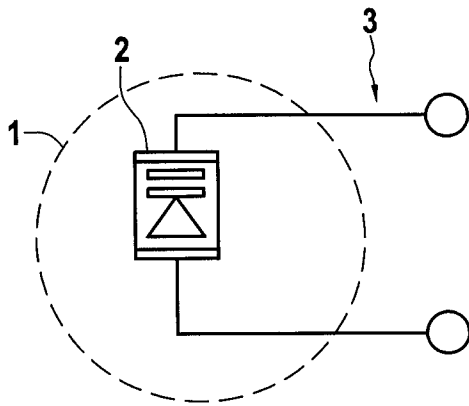


FIG. 1

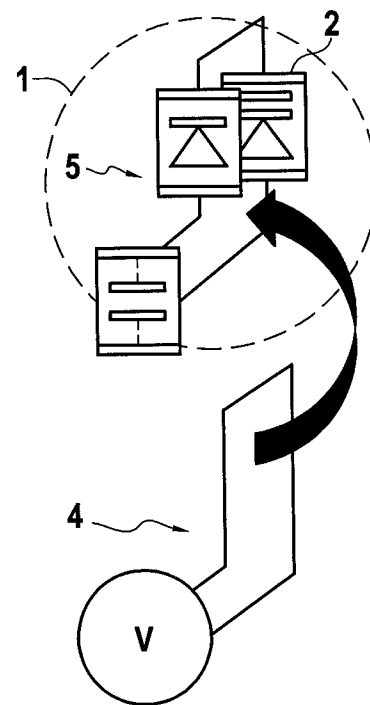


FIG. 2

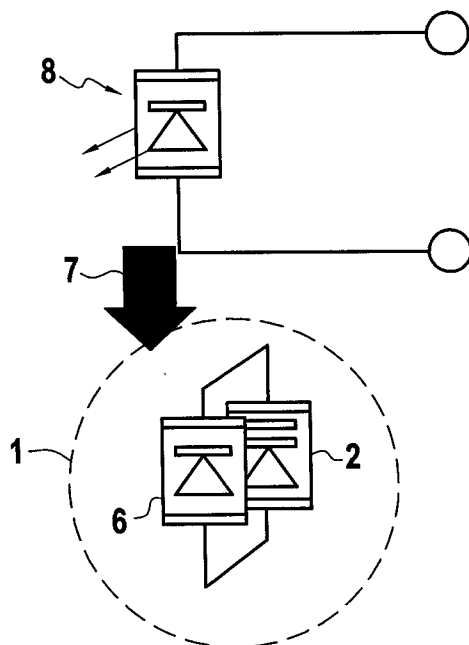
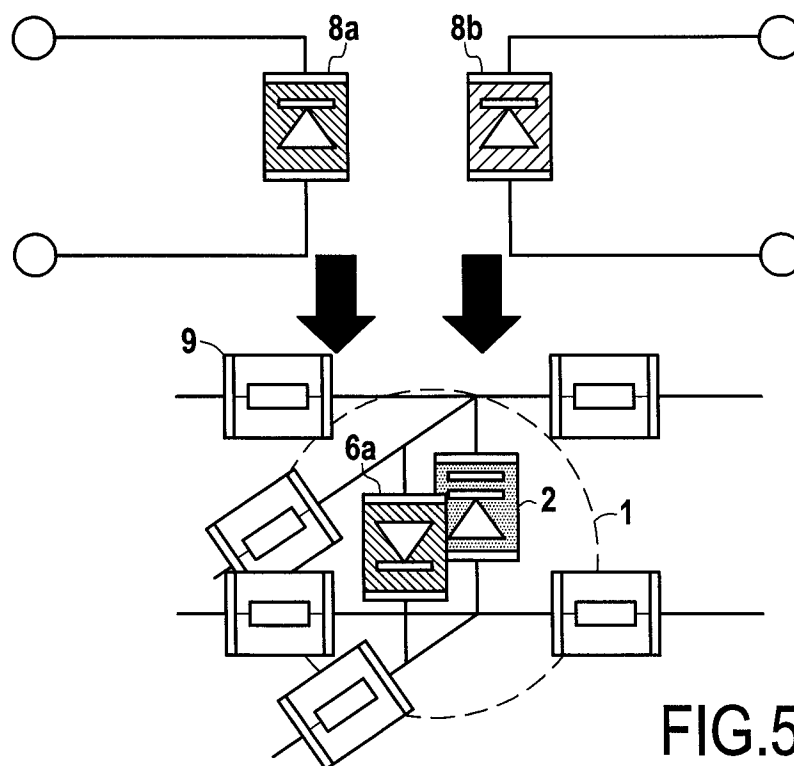
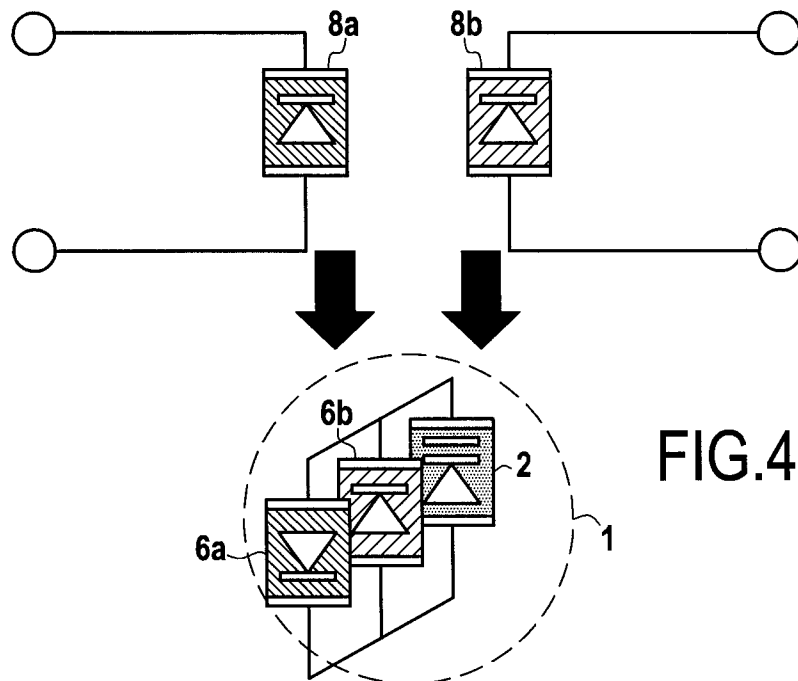


FIG. 3

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3/5

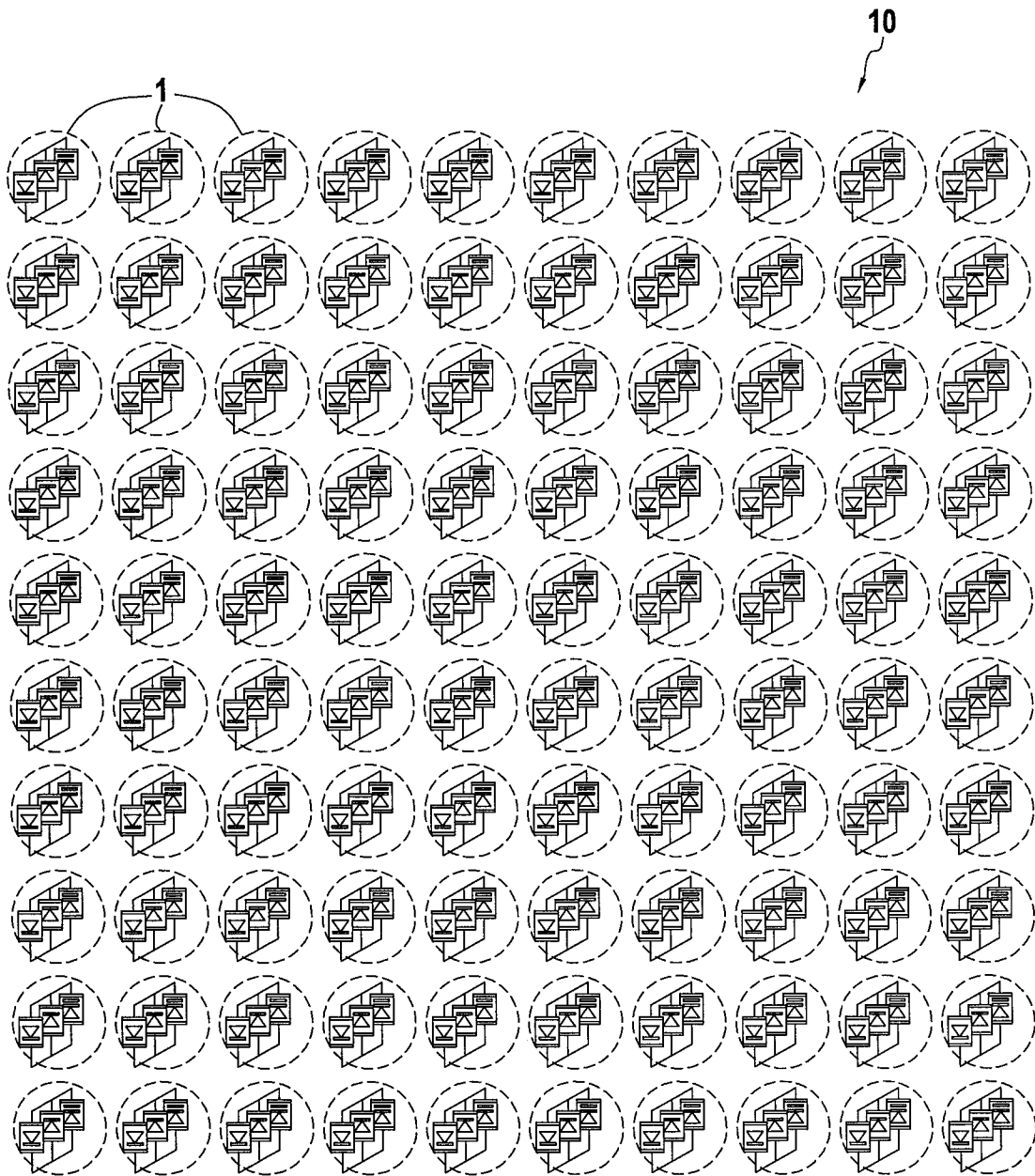


FIG.6

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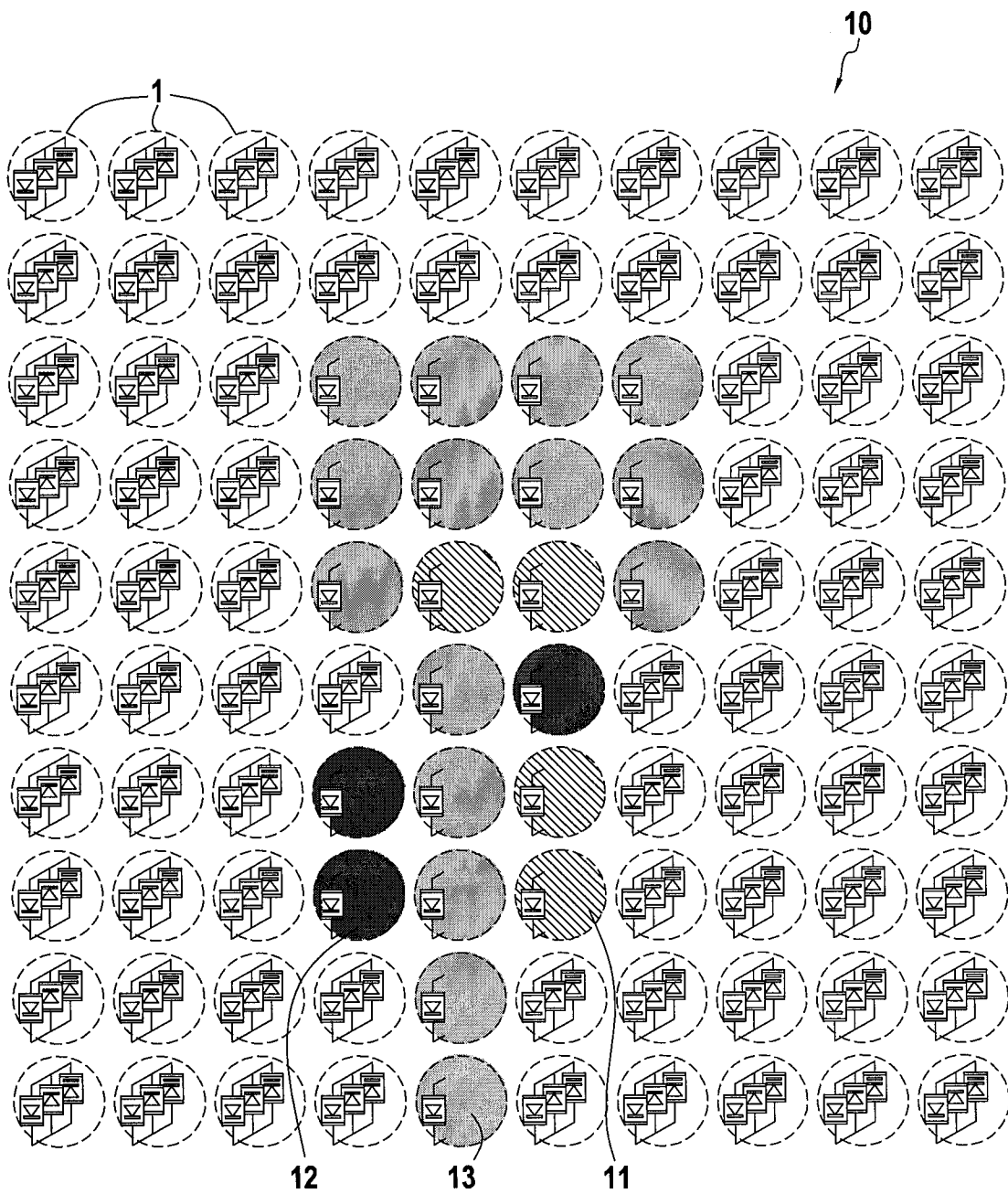


FIG.7

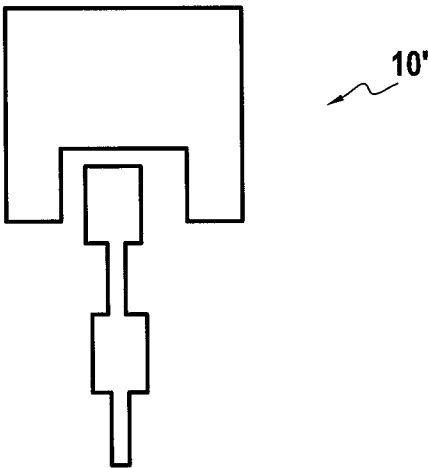


FIG.8

INTERNATIONAL SEARCH REPORT

International application No
PCT/EP2017/054672

A. CLASSIFICATION OF SUBJECT MATTER
INV. H01Q15/00
ADD.

According to International Patent Classification (IPC) or to both national classification and IPC

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)
H01Q

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched

Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)

EPO-Internal, INSPEC, COMPENDEX

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US 2010/060544 A1 (PENEV VLADIMIR [US] ET AL) 11 March 2010 (2010-03-11) paragraph [0007] - paragraph [0013]; figures 1, 3A paragraphs [0084], [0085] paragraph [0042] paragraph [0050] ----- -/--	1-12



Further documents are listed in the continuation of Box C.



See patent family annex.

* Special categories of cited documents :

"A" document defining the general state of the art which is not considered to be of particular relevance

"E" earlier application or patent but published on or after the international filing date

"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)

"O" document referring to an oral disclosure, use, exhibition or other means

"P" document published prior to the international filing date but later than the priority date claimed

"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention

"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone

"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art

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Date of the actual completion of the international search

10 November 2017

Date of mailing of the international search report

20/11/2017

Name and mailing address of the ISA/

European Patent Office, P.B. 5818 Patentlaan 2
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Fax: (+31-70) 340-3016

Authorized officer

Gill, Richard

INTERNATIONAL SEARCH REPORT

International application No
PCT/EP2017/054672

C(Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	JING LIANG ET AL: "Microstrip Patch Antennas on Tunable Electromagnetic Band-Gap Substrates", IEEE TRANSACTIONS ON ANTENNAS AND PROPAGATION, IEEE SERVICE CENTER, PISCATAWAY, NJ, US, vol. 57, no. 6, 1 June 2009 (2009-06-01), pages 1612-1617, XP011281632, ISSN: 0018-926X, DOI: 10.1109/TAP.2009.2019928 abstract; figures 1,3 -----	1-12
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INTERNATIONAL SEARCH REPORT

Information on patent family members

International application No

PCT/EP2017/054672

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